

## FRED

### Ultrafast Soft Recovery Diode

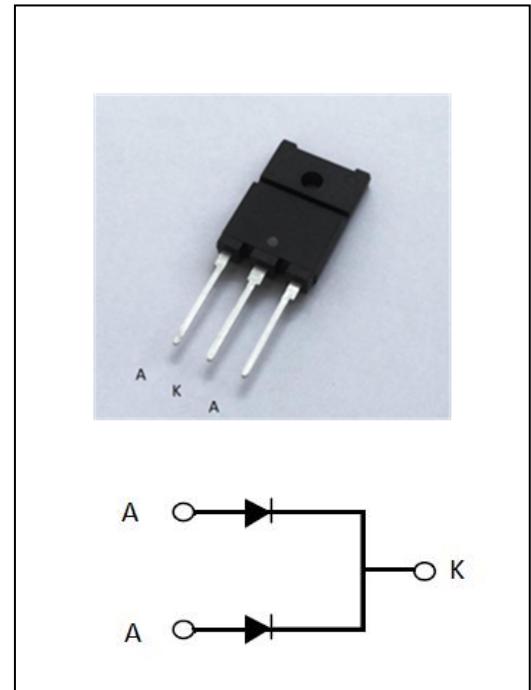
#### FEATURES:

- Ultrafast Recovery
- 175°C operating junction temperature
- Designed and qualified for industrial level

#### Benefits:

- Reduced RFI and EMI
- Higher frequency operation
- Reduced snubbing
- Reduced part count

Product Summary	
V <sub>R</sub>	200 V
I <sub>F(AV)</sub>	2*15A
t <sub>rr</sub>	18ns



#### Description/Applications

These diodes are optimized to less losses and EMI/RFI in high frequency power conditioning system. The soft recovery behavior of the diodes offers the need as snubber in most applications. These devices are ideally suited for HF welding power converters and other applications where the switching losses are not significant portion of the total losses.

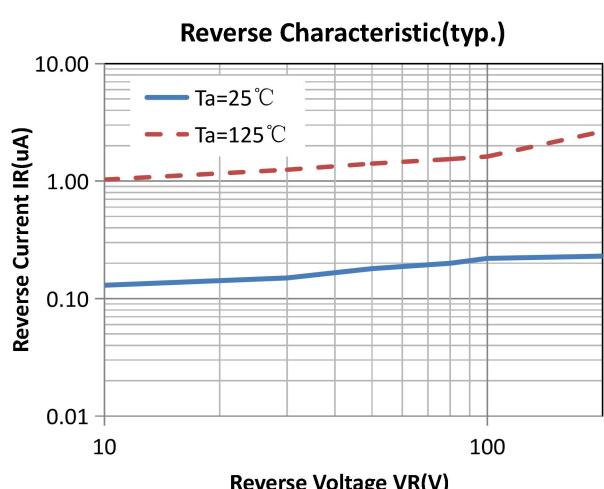
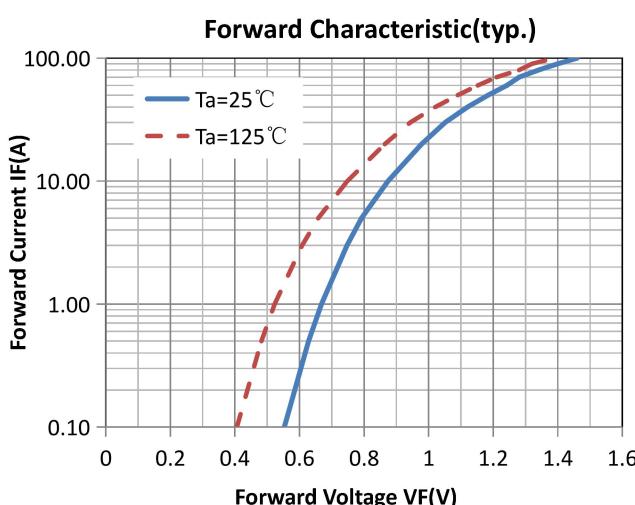
Absolute Maximum Ratings				
Parameter	Symbol	Test Conditions	Values	Units
Repetitive peak reverse voltage	V <sub>RRM</sub>		200	V
Continuous forward current	I <sub>F(AV)</sub>	T <sub>c</sub> = 25°C	30	A
Single pulse forward current	I <sub>FSM</sub>	T <sub>c</sub> = 25°C	150	
Maximum repetitive forward current	I <sub>FRM</sub>	Square wave, 20kHz	50	
Operating junction	T <sub>j</sub>		175	°C
Storage temperatures	T <sub>stg</sub>		-55 to +175	°C

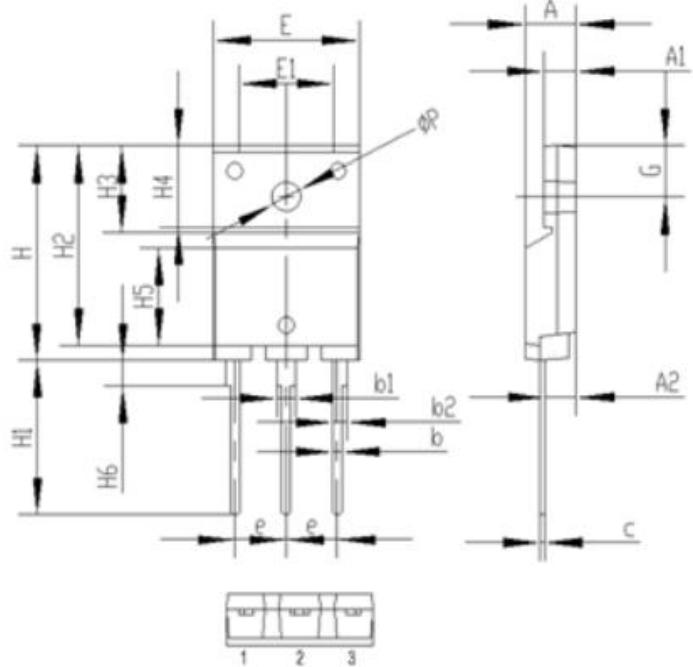
**Electrical characteristics (Ta=25°C unless otherwise specified)**

Parameter	Symbol	Test Conditions	Min	Typ.	Max.	Units
Breakdown voltage Blocking voltage	V <sub>BR</sub> , V <sub>R</sub>	I <sub>R</sub> =100μA	200			V
Forward voltage (Per Diode)	V <sub>F</sub>	I <sub>F</sub> =15 A		0.90	1.0	
		I <sub>F</sub> =15 A, T <sub>j</sub> =125°C		0.80	0.9	
Reverse leakage current(Per Diode)	I <sub>R</sub>	V <sub>R</sub> = V <sub>RRM</sub>			10	μA
		T <sub>j</sub> =150°C, V <sub>R</sub> =200V			100	
Reverse recovery time(Per Diode)	t <sub>rr</sub>	I <sub>F</sub> =0.5A, I <sub>R</sub> =1A, I <sub>RR</sub> =0.25A		25	30	ns
		I <sub>F</sub> =1A, V <sub>R</sub> =30V, di/dt =200A/us		18	30	

**Thermal characteristics**

Paramter	Symbol	Typ	Units
Junction-to-Case	R <sub>θJC</sub>	0.8	°C/W

**Electrical performance (typic)**


**Package Information****TO-3PF PACKAGE**

Symbol	Dimensions(millimeters)	
	Min.	Max.
A	5.30	5.70
A1	3.25	3.65
A2	3.15	3.55
b	0.80	1.20
b1	1.85	2.15
b2	1.45	1.75
c	0.40	0.80
e	5.25	5.65
E	15.4	15.8
E1	10.0	10.4
H	22.5	23.2
H1	16.0	17.0
H2	21.2	21.6
H3	9.10	9.50
H4	8.55	8.95
H5	10.20	10.60
H6	2.55	2.85
G	5.30	5.70
ΦP	3.00	3.40